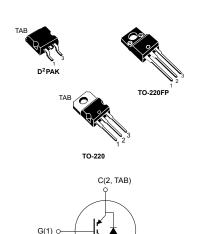


Datasheet

N-channel 600 V, 7 A, very fast IGBT



Features

- Low V_{CE(sat)}
- Low C_{RES}/C_{IES} ratio (no cross-conduction susceptibility)
- · Very soft ultra fast recovery antiparallel diode
- · High-frequency operation

Applications

- High-frequency inverters
- · SMPS and PFC in both hard switch and resonant topologies
- Motor drivers

Description

Using the latest high-voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs characterized by an outstanding performance. The "H" suffix identifies a family optimized for high-frequency applications which achieve very high switching performances (reduced tfall) while mantaining a low voltage drop.



E(3)

NG1E3C2T

Product status link
STGB6NC60HDT4
STGF6NC60HD
STGP6NC60HD



1 Electrical ratings

Table 1. Absolute maximum ratings

Country of	Value		114	
Symbol	Parameter	D ² PAK, TO-220	TO-220FP	Unit
V _{CES}	Collector-emitter voltage (V _{GE} = 0 V)	60	00	V
	Continuous collector current at T _C = 25 °C	15	6	
I _C	Continuous collector current at T _C = 100 °C	7	3	Α
I _{CM} ⁽¹⁾	Collector current (pulsed)	21		Α
V _{GE}	Gate-emitter voltage	±20		V
I _F	Diode RMS forward current at T _C = 25 °C	1	0	Α
P _{TOT}	Total power dissipation at T _C = 25 °C	62.5	25	W
V _{ISO}	Insulation withstand voltage (RMS) from all three leads to external heat sink (t = 1 s; $T_C = 25 ^{\circ}C$)	2.5		kV
T _{STG}	Storage temperature range	-55 to 150		°C
TJ	Operating junction temperature range	-55 [0 150	°C

^{1.} Pulse width is limited by maximum junction temperature.

Table 2. Thermal data

Cymhal	Baramatar	Val	l lmié	
Symbol	Parameter	D ² PAK, TO-220	TO-220FP	Unit
R _{thJC}	Thermal resistance junction-case 2		5	°C/W
R _{thJA}	Thermal resistance junction-ambient	62.5		°C/W

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2 Electrical characteristics

 T_C = 25 °C unless otherwise specified

Table 3. Static characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)CES}	Collector-emitter breakdown voltage	V _{GE} = 0 V, I _C = 1 mA	600			V
Vorces	Collector-emitter saturation	V _{GE} = 15 V, I _C = 3 A		1.9	2.5	V
V _{CE(sat)}	voltage	V _{GE} = 15 V, I _C = 3 A, T _C = 125 °C		1.7		'
$V_{GE(th)}$	Gate threshold voltage	$V_{CE} = V_{GE}, I_{C} = 250 \mu A$	3.75		5.75	V
1	Collector cut-off current	V _{GE} = 0 V, V _{CE} = 600 V			10	μA
ICES		V_{GE} = 0 V, V_{CE} = 600 V, T_{C} = 125 °C ⁽¹⁾			1	mA
I _{GES}	Gate-emitter leakage current	V _{GE} = ±20 V, V _{CE} = 0 V			±100	nA

^{1.} Defined by design, not subject to production test

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{ies}	Input capacitance		-	205	-	
C _{oes}	Output capacitance	V_{CE} = 25 V, f = 1 MHz, V_{GE} = 0 V	-	32	-	pF
C _{res}	Reverse transfer capacitance		-	5.5	-	
Qg	Total gate charge		-	13.6	-	
Q _{ge}	Gate-emitter charge	V _{CE} = 390 V, I _C = 3 A, V _{GE} = 0 to 15 V (see Figure 18. Gate charge test circuit)	-	3	-	nC
Q_{gc}	Gate-collector charge	,	-	6	-	
I _{CL}	Turn-off SOA minimum current	V_{clamp} = 390 V, T_J = 150 °C, R_G = 10 Ω , V_{GE} = 15 V	-	19	-	Α

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Table 5. Switching characteristics (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time	$V_{CC} = 390 \text{ V, } I_{C} = 3 \text{ A, } R_{G} = 10 \Omega,$	-	12	-	
t _r	Current rise time	V _{GE} = 15 V (see Figure 17. Test circuit for	-	5	-	ns
(di/dt) _{on}	Turn-on current slope	inductive load switching)	-	612	-	A/µs
t _{d(on)}	Turn-on delay time	V_{CC} = 390 V, I_{C} = 3 A, R_{G} = 10 Ω ,	-	13	-	
t _r	Current rise time	V _{GE} = 15 V, T _J = 125 °C (see Figure 17. Test circuit for inductive	-	4.3	-	ns
(di/dt) _{on}	Turn-on current slope	load switching)	-	560	-	A/µs
$t_r(V_{off})$	Off voltage rise time	$V_{CC} = 390 \text{ V}, I_{C} = 3 \text{ A}, R_{G} = 10 \Omega,$	-	40	-	
t _d (off)	Turn-off delay time	V _{GE} = 15 V (see Figure 17. Test circuit for	-	76	-	ns
t _f	Current fall time	inductive load switching)	-	100	-	
$t_r(V_{off})$	Off voltage rise time	V_{CC} = 390 V, I_{C} = 3 A, R_{G} = 10 Ω ,	-	60	-	
t _d (off)	Turn-off delay time	V _{GE} = 15 V, T _J = 125 °C (see Figure 17. Test circuit for inductive	-	98	-	ns
t _f	Current fall time	load switching)	-	124	-	

Table 6. Switching energy (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
E _{on} (1)	Turn-on switching energy	$V_{CC} = 390 \text{ V}, I_{C} = 3 \text{ A}, R_{G} = 10 \Omega,$	-	20	-	
E _{off} (2)	Turn-off switching energy	V _{GE} = 15 V (see)Figure 17. Test circuit	-	68	-	μJ
E _{ts}	Total switching energy	for inductive load switching	-	88	-	
E _{on} (1)	Turn-on switching energy	V_{CC} = 390 V, I_C = 3 A, R_G = 10 Ω ,	-	37	-	
E _{off} (2)	Turn-off switching energy	V_{GE} = 15 V, T_{J} = 125 °C (see)Figure 17. Test circuit for inductive load switching	-	93	-	μJ
E _{ts}	Total switching energy		-	130	-	

^{1.} Including the reverse recovery of the diode

Table 7. Collector-emitter diode

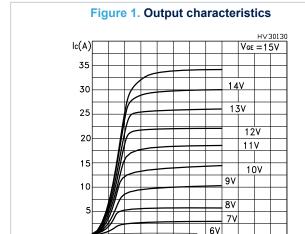
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V 5	Forward on voltage	I _f = 1.5 A	-	1.6	2.1	V
V†	V _f Forward on-voltage	I _f = 1.5 A, Tj = 125 °C	-	1.3		V
t _{rr}	Reverse recovery time	I _f = 3 A ,V _R = 40 V, di/dt = 100 A/µs (see Figure 20. Diode reverse recovery	-	21		ns
Q _{rr}	Reverse recovery charge		-	14		nC
I _{rrm}	Reverse recovery current	waveform)	-	1.36		Α
t _{rr}	Reverse recovery time	$I_f = 3 \text{ A}, V_R = 40 \text{ V}, T_j = 125 ^{\circ}\text{C}, \text{ di/dt} =$	-	34		ns
Q _{rr}	Reverse recovery charge	100 A/µs (see Figure 20. Diode reverse	-	32		nC
I _{rrm}	Reverse recovery current	recovery waveform)	-	1.88		Α

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^{2.} Including the tail of the collector current



2.1 Electrical characteristics (curves)



10

15

20

25 V_{ce}(V)

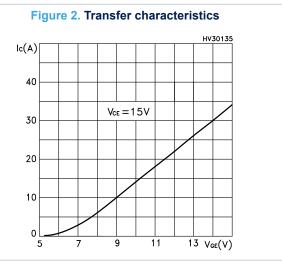


Figure 3. Transconductance

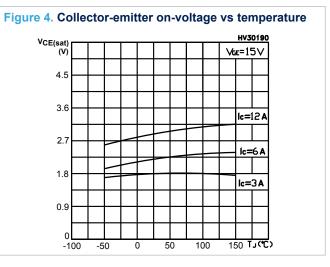
HV30240

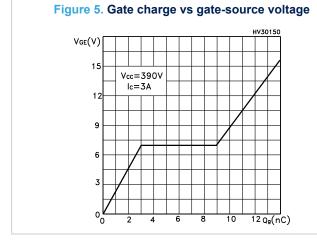
VcE=15V

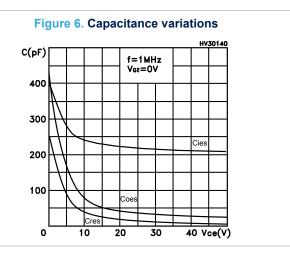
TJ=-50°C

150°C

150°C







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Figure 7. Normalized gate threshold voltage vs temperature

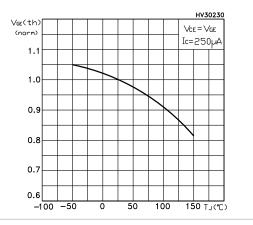


Figure 8. Collector-emitter on voltage vs collector current

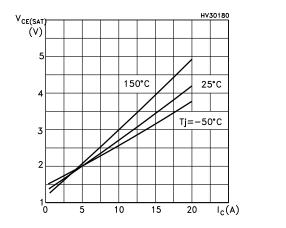


Figure 9. Normalized breakdown voltage vs temperature

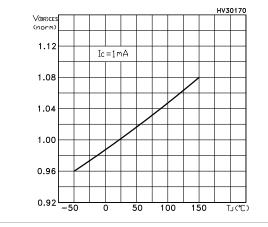


Figure 10. Switching energy vs temperature

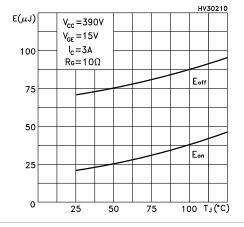


Figure 11. Switching energy vs gate resistance

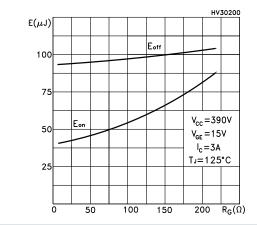
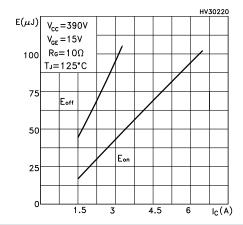


Figure 12. Switching energy vs collector current



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Figure 13. Thermal impedance for TO-220 / D²PAK

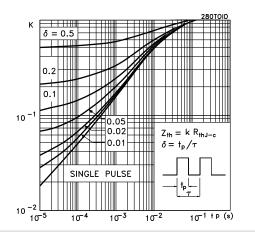


Figure 14. Turn-off SOA

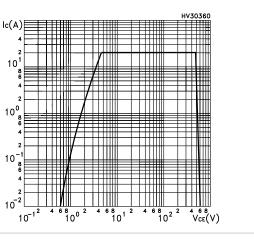


Figure 15. Thermal impedance for TO-220FP

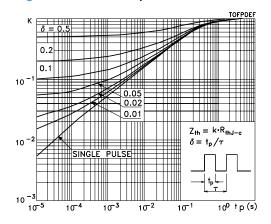
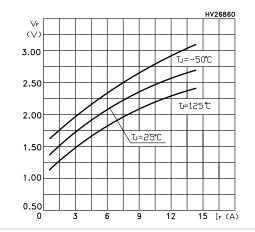


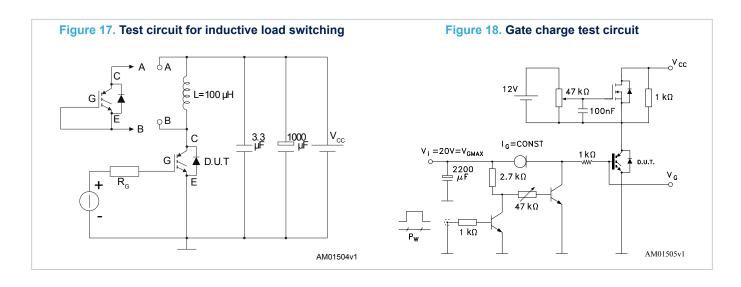
Figure 16. Emitter-collector diode characteristics

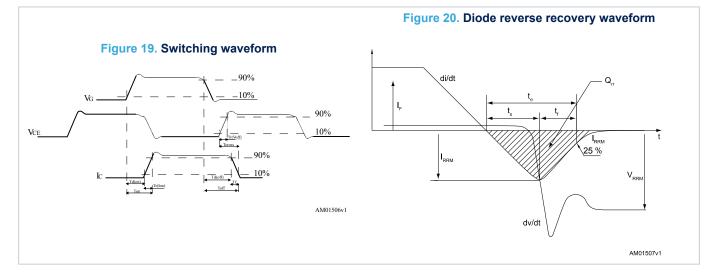


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3 Test circuits





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4 Package information

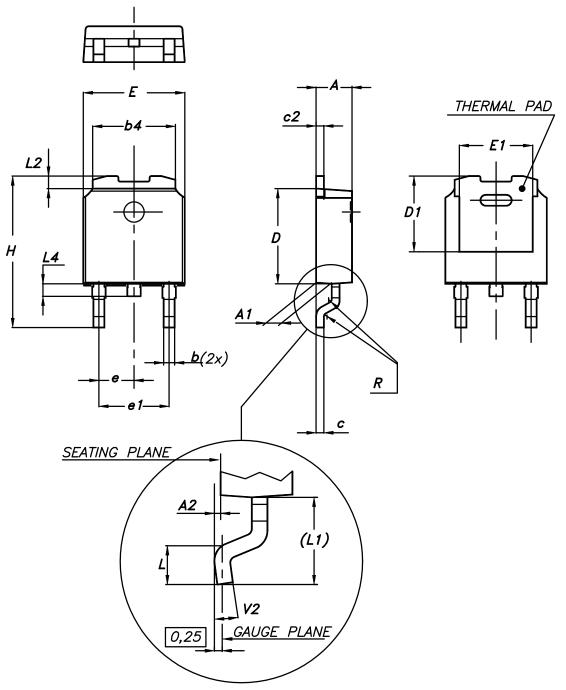
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

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4.1 D²PAK (TO-263) type A package information

Figure 21. DPAK (TO-252) type A package outline



0068772_A_25



Table 8. DPAK (TO-252) type A mechanical data

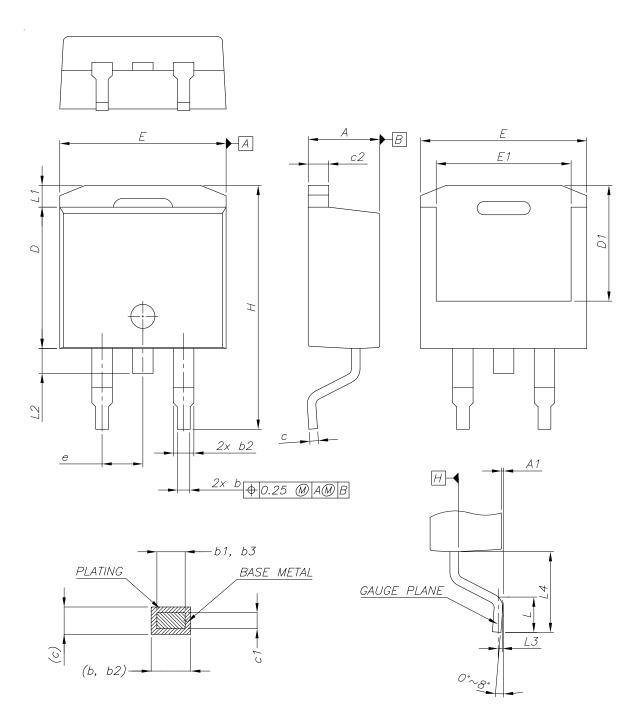
Dim.		mm	
Dim.	Min.	Тур.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1	4.95	5.10	5.25
Е	6.40		6.60
E1	4.60	4.70	4.80
е	2.159	2.286	2.413
e1	4.445	4.572	4.699
Н	9.35		10.10
L	1.00		1.50
(L1)	2.60	2.80	3.00
L2	0.65	0.80	0.95
L4	0.60		1.00
R		0.20	
V2	0°		8°

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4.2 D²PAK (TO-263) type B package information

Figure 22. D²PAK (TO-263) type B package outline



0079457_25_B



Table 9. D²PAK (TO-263) type B mechanical data

Dim.		mm	
DIM.	Min.	Тур.	Max.
A	4.36		4.56
A1	0		0.25
b	0.70		0.90
b1	0.51		0.89
b2	1.17		1.37
b3	1.36		1.46
С	0.38		0.694
c1	0.38		0.534
c2	1.19		1.34
D	8.60		9.00
D1	6.90		7.50
E	10.15		10.55
E1	8.10		8.70
е		2.54 BSC	
Н	15.00		15.60
L	1.90		2.50
L1			1.65
L2			1.78
L3		0.25	
L4	4.78		5.28

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9.75 16.9 1.6 2.54 5.08

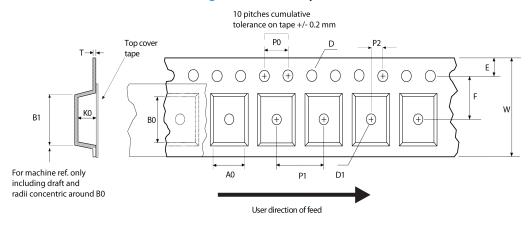
Figure 23. D²PAK (TO-263) recommended footprint (dimensions are in mm)

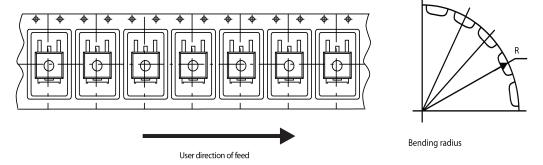
Footprint



4.2.1 Packing information

Figure 24. D²PAK tape outline



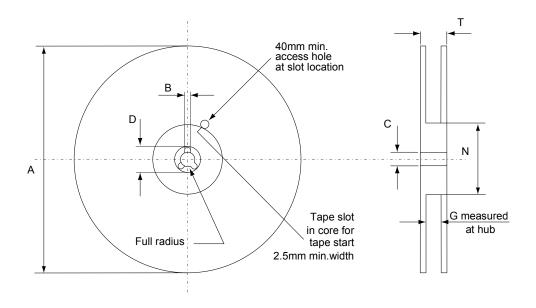


AM08852v1

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Figure 25. D²PAK reel outline



AM06038v1

Table 10. D2PAK tape and reel mechanical data

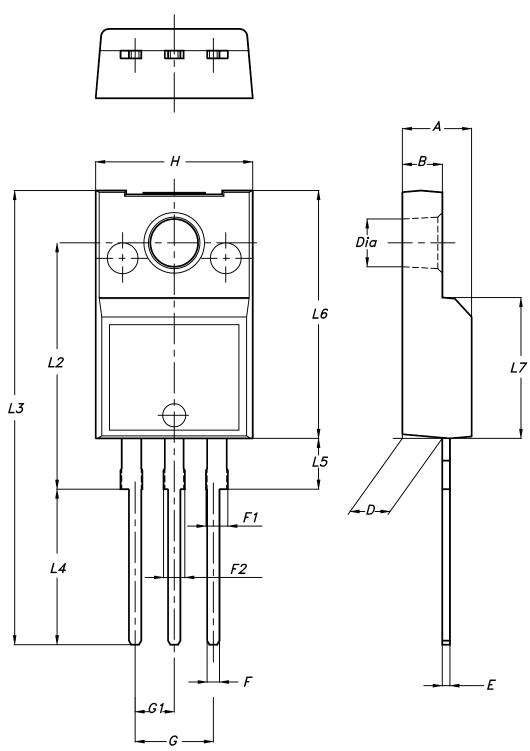
Таре				Reel	
Dim.	mı	m	Dim.	m	ım
Diiii.	Min.	Max.	D	Min.	Max.
A0	10.5	10.7	Α		330
В0	15.7	15.9	В	1.5	
D	1.5	1.6	С	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	Т		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base	quantity	1000
P2	1.9	2.1	Bulk o	quantity	1000
R	50				
Т	0.25	0.35			
W	23.7	24.3			

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4.3 TO-220FP package information

Figure 26. TO-220FP package outline



7012510_Rev_12_B



Table 11. TO-220FP package mechanical data

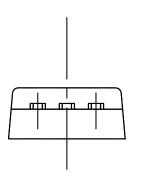
Dim.		mm	
Dim.	Min.	Тур.	Max.
Α	4.4		4.6
В	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
Н	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

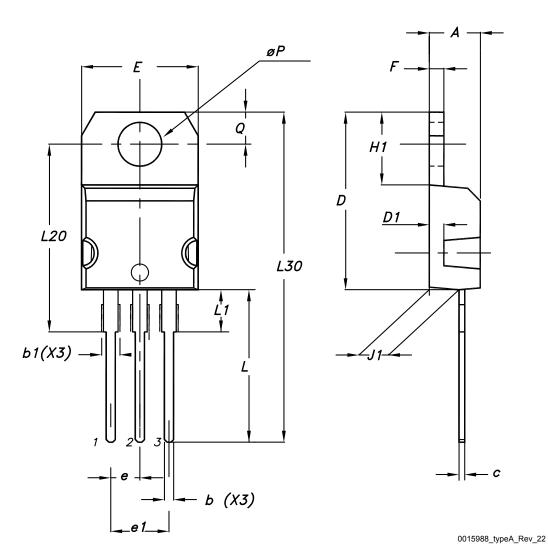
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4.4 TO-220 type A package information

Figure 27. TO-220 type A package outline





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Table 12. TO-220 type A package mechanical data

Dim.	mm			
DIM.	Min.	Тур.	Max.	
A	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.55	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10.00		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40		2.72	
L	13.00		14.00	
L1	3.50		3.93	
L20		16.40		
L30		28.90		
øΡ	3.75		3.85	
Q	2.65		2.95	

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5 Ordering information

Table 13. Ordering information

Order code	Marking	Package	Packing
STGB6NC60HDT4	GB6NC60HD	D²PAK	Tape and reel
STGF6NC60HD	GF6NC60HD	TO-220FP	Tube
STGP6NC60HD	GP6NC60HD	TO-220	Tube

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Revision history

Table 14. Document revision history

Date	Revision	Changes
28-Nov-2005	1	First release
07-Mar-2006	2	Complete version
31-Jul-2006	3	Modified Figure 10.
26-Apr-2007	4	Inserted package I ² PAK
		Part number STGB6NC60HD-1 has been moved to a separate datasheet.
	5	Updated information on cover page.
20-Nov-2017		Updated Table 2: "Absolute maximum ratings" and Table 4: "Static characteristics".
		Updated Section 2.1: "Electrical characteristics (curves)".
		Updated Section 4: "Package information".
		Minor text changes
23-Oct-2018	6	Updated title in coverpage and Table 4. Dynamic characteristics.
		Minor text changes.

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		4.2.1	Packing information	15
			20FP package information	
	4.4	TO-22	20 package information	
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Re	vision	history	/	



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